

Abstract Submitted  
for the MAR17 Meeting of  
The American Physical Society

**Large Scale GW Calculations Including Electron-Phonon Interactions**<sup>1</sup> RYAN MCAVOY, Institute for Molecular Engineering, University of Chicago, MARCO GOVONI, GIULIA GALLI, Institute for Molecular Engineering, University of Chicago; Materials Science Division, Argonne National Laboratory — Including the effect of electron-phonon coupling in first principle electronic structure calculations is crucial for the accurate prediction of band-gaps and temperature dependent carrier lifetimes. We present results for the electronic properties of condensed and molecular systems, including electron-phonon coupling, obtained by merging GW calculations [1] of eigenvalues and an efficient implementation of the Fan-Migdal-Debye-Waller self-energy. Our implementation does not require summation over virtual states and inversion of large dielectric matrices. Advantages of the algorithm presented here over standard techniques and its scalability will be discussed. [1] Govoni, Marco, and Giulia Galli. "Large scale GW calculations." *Journal of chemical theory and computation* 11, no. 6 (2015): 2680-2696.

<sup>1</sup>This work was supported by MICCoM, as part of the Computational Materials Sciences Program funded by the U.S. Department of Energy, Office of Science, Basic Energy Sciences, Materials Sciences and Engineering Division, under grant DOE/BES 5J-30161-0010A

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Date submitted: 11 Nov 2016

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